

Description

The TSSIXR28 SIP products using system-level packaging technology, integrated multi-gigasample RF data converter modules: include RF-ADCs 、 RF-DACs and soft-decision forward error correction(SD-FEC); integrated a feature-rich 64-bit quad-core ARM® Cortex[™]-A53 and dual-core ARM Cortex-R5 based processing system with 8GByte capacity on-chip DDR4-SDRAM external memory; integrated a large-scale programmable logic unit, also equipped with a 8GByte capacity on-chip DDR4-SDRAM external memory; integrated a 4Gb capacity QSPI NOR Flash used for system booting and configuration. All the resources above together form a powerful RF direct-sampling + processing micro-system in a single package. Greatly improve the density and flexibility of the system, at the same time, simplify the design 、 reduce design difficulty and shorten the product development cycle.

Features

- 8 channel RF-ADCs
 - 12-bit resolution;
 - Maximum sample rate: 4.096GSPS
 - Full complex mixers: 48-bit NCO per RF-ADC
 - direct-sampling RF capability
- 8 channel RF-DACs
 - 14-bit resolution
 - Maximum sample rate: 6.554GSPS
 - Full complex mixers: 48-bit NCO per RF-DAC
 - Up to 5GHz RF output
 - 4GHz full power output bandwidth
- Soft Decision Forward Error Correction (SD-FEC)
 - LDPCDecoding/Encoding
 - TurboDecoding
- Multi processor units
 - APU: 64-bitquad-coreArmCortex-A53MPCores
 Operatingtargetfrequency:upto1.3GHz
 Single and double precision floating point operations
 32KB level 1 Cache
 1MBlevel2
 Cache
 - RPU: Dual-coreArmCortex-R5MPCores
 Operatingtargetfrequency:Upto600MHz
 Single and double precision floating point operations
 32KB level 1 Cache
 - Externalmemory: DDR4 SDRAM 8GBytecapacity 72bit width, ECC supported
- Feature-rich I/O Peripherals
 - PCIe: x1, x2, or x4 at Gen1 or Gen2 rates
 - SATA3.1: up to 6.0Gb/s data rates
 - USB3.0: 2 controller, up to 5.0Gb/s data rates
 - SD/SDIO3.0: eMMC4.51 supported, HS200: up to 200MHz
 - UART: Programmable baud rate generator
 - CAN: Conforms to CAN2.0A and CAN2.0B standard, Bit rates up to 1Mb/s

- On-chip QSPI NOR FLASH
 - Forsystembootandconfiguration
 - 4Gbcapacity:2Gb*2pcs
 - Programmable logic
 - Slice: 930,300
 - DSP Slice: 4,272
 - Block-RAM: 38Mb
 - PCIE: Gen3, 2channel
 - I/O: 143 (High-Performance) 48 (Hi-Range)
 - High-SpeedSerialTransceivers: GTY16channels
 - Externalmemorys: DDR4SDRAM
 - 8GBytecapacity 72bit width, ECC supported
- Packaging and dimensions
 - BGA1760
 - 47.0mm*70.0mm

Benefits

- Compact package, 62% space savings in PCB area based on the same performance
- Simplify design, avoid complex and time-consuming PCB Layout
- work, accelerate product development processes
- Standardized, modular design, benefit upgrade and integration

Applications

- 5G and LTE Wireless
- Remote-PHY for Cable Access DOCSIS 3.1
- Phased Array Radar
- Satellite Communications
- Military Communications
- Test & Measurement
- LiDAR technologies



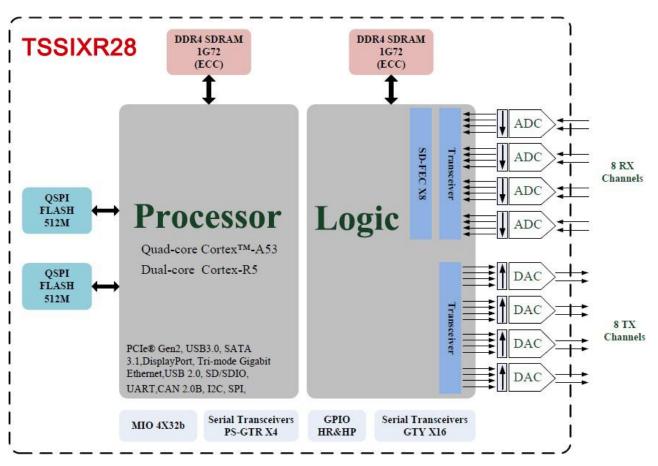


Figure 1 – Functional block diagram for TSSIXR28

NOTES: All passive components shown in the block diagram are included inside the 1670 BGA package, with essentially Decoupling Capacitors and Terminal Resistors in chip.

Development Kits

Xilinx Vivado Design Suite: System Edition, Version 2018.1 or later;

Xilinx SDK;

PetaLinux;

Ordering information

	IS SI XR28 - BG1760 I
TechSDX	
SI:SiP	
XR28:Part Number ————	
BG1760:1760Ball BGA	
l:Temperature Range Industrial -40°C ~ 100°C	